L Number	Hits	Search Text	DB_	Time stamp
-	19	(("6,255,166") or ("5,408,115") or ("5,969,383") or	USPAT;	2004/05/11 11:08
		("5,422,504") or ("5,494,838") or ("6,177,318") or	US-PGPUB;	
		("6,248,633") or ("2002-0100929") or ("2002-0127805") or	EPO; JPO;	
		("6,413,821") or ("6,518,124") or ("2003-0054610") or	DERWENT;	
		("2003-0057505") or ("2003-0058705") or ("2003-0060011")	IBM_TDB	
		or ("2003-0190805") or ("2003-0186505") or		
		("2003-0166321") or ("2003-0157767") or ("2003-0166322")		
		or ("2003-0166320") or ("2003-0211691")).PN.		
-	24	(("20020100929") or ("20020127805") or ("20030054610") or	USPAT;	2004/05/11 11:11
		("20030057505") or ("20030058705") or ("20030060011") or	US-PGPUB;	
	ŀ	("20030190805") or ("20030186505") or ("20030166321") or	EPO; JPO;	
		("20030157767") or ("20030166322") or ("20030166320") or	DERWENT;	
		("2003-0211691")).PN.	IBM_TDB	
-	288765	(metal adj oxide adj nitride adj oxide adj semiconductor) or	USPAT;	2004/05/12 08:58
		MONOS	US-PGPUB;	
	•		EPO; JPO;	
			DERWENT;	
i			IBM_TDB	
-	291074	(metal adj oxide adj nitride adj oxide adj semiconductor) or	USPAT;	2004/05/12 09:01
		MONOS or (silicon adj oxide adj nitride adj oxide adj silicon)	US-PGPUB;	
		or SONOS	EPO; JPO;	
			DERWENT;	
	750		IBM_TDB	0004/05/40 00 00
-	759	((metal adj oxide adj nitride adj oxide adj semiconductor) or	USPAT;	2004/05/12 09:02
		MONOS or (silicon adj oxide adj nitride adj oxide adj silicon)	US-PGPUB;	
		or SONOS) and (control adj gate)	EPO; JPO;	
			DERWENT;	
			IBM_TDB	0004/05/40 00:00
-	33	((metal adj oxide adj nitride adj oxide adj semiconductor) or	USPAT; US-PGPUB;	2004/05/12 09:03
		MONOS or (silicon adj oxide adj nitride adj oxide adj silicon)		
	1	or SONOS) and ((control adj gate) with (word adj gate) with ONO)	EPO; JPO; DERWENT;	
			IBM TDB	
		<u> </u>	ם סוד ואוסון	L